

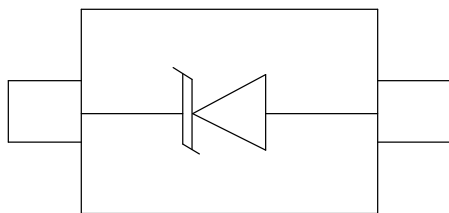
Description

The DCxx71D3UH is a high power uni-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive lines. The DCxx71D3UH complies with the IEC 61000-4-2 (ESD) standard with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into a 3 pin SOD-323 lead free package. The leads are finished with NiPdAu. Each device will protect one line. The combination of small size, and high surge capability makes them ideal for use in applications such as cellular phones, LCD displays, USB, and multimedia card interfaces.

Mechanical Characteristics

- ◆ Package: SOD-323
- ◆ Lead Finish: NiPdAu
- ◆ Case Material: "Green" Molding Compound.
- ◆ UL Flammability Classification Rating 94V-0
- ◆ Moisture Sensitivity: Level 3 per J-STD-020
- ◆ Terminal Connections: See Diagram Below
- ◆ Marking Information: See Below

Dimensions and Pin Configuration



SOD-323(Top View)
Circuit and Pin Schematic

Features

- ◆ 2200W peak pulse power (8/20 μs)
- ◆ Protects one data or power line
- ◆ Operating voltage: 3.3V, 5V, 7V, 12V, 15V, 18V, 24V, 36V
- ◆ Ultra low clamping voltage
- ◆ High peak pulse current capability
- ◆ Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30\text{kV}$
 - Contact discharge: $\pm 30\text{kV}$
 - IEC61000-4-4 (EFT) 80A (5/50ns)
- ◆ RoHS Compliant

Applications

- ◆ Power Management
- ◆ Battery Protection
- ◆ Power Supply Protection
- ◆ Mobile Phones and Accessories
- ◆ USB VBus
- ◆ Hand Held Portable Applications

Marking Information



xxD: Device Marking Code
Bar denotes Cathode

Ordering Information

Part Number	Marking	Packaging	Reel Size
DCxx71D3UH	xxD	3000/Tape & Reel	7 inch

Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
ESD per IEC 61000-4-2 (Air)	V _{ESD}	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	T _J	-40 to +85	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

DC0371D3UH (Marking Code: 37D)						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			3.3	V	
Breakdown Voltage	V _{BR}	3.5			V	I _T = 1mA
Reverse Leakage Current	I _R			1.0	μA	V _{RWM} = 3.3V
Forward Voltage	V _F		1.0	1.2	V	I _F = 10mA
Clamping Voltage	V _C			15	V	I _{PP} = 140A (8 x 20μs pulse)
Peak Pulse Current	I _{PP}			140	A	t _p = 8/20μs
Junction Capacitance	C _J			750	pF	V _R = 0V, f = 1MHz

DC0571D3UH (Marking Code: 57D)						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Breakdown Voltage	VBR	6			V	IT = 1mA
Reverse Leakage Current	IR			1.0	μA	VRWM = 5V
Forward Voltage	VF		1.0	1.2	V	IF=10mA
Clamping Voltage	VC			17	V	I _{PP} = 130A (8 x 20μs pulse)
Peak Pulse Current	I _{PP}			130	A	tp=8/20μs
Junction Capacitance	CJ			650	pF	VR = 0V, f = 1MHz

DC0771D3UH (Marking Code: 77D)						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			7	V	
Breakdown Voltage	VBR	7.5			V	IT = 1mA
Reverse Leakage Current	IR			0.5	μA	VRWM = 7V
Forward Voltage	VF		1.0	1.2	V	IF=10mA
Clamping Voltage	VC			20	V	I _{PP} = 115A (8 x 20μs pulse)
Peak Pulse Current	I _{PP}			115	A	tp=8/20μs
Junction Capacitance	CJ			550	pF	VR = 0V, f = 1MHz

DC1271D3UH (Marking Code: 72D)						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V_{RWM}			12	V	
Breakdown Voltage	V_{BR}	12.6			V	$I_T = 1\text{mA}$
Reverse Leakage Current	I_R			0.1	μA	$V_{RWM} = 12\text{V}$
Forward Voltage	V_F		1.0	1.2	V	$I_F = 10\text{mA}$
Clamping Voltage	V_C			28	V	$I_{PP} = 80\text{A}$ (8 x 20 μs pulse)
Peak Pulse Current	I_{PP}			80	A	$t_p = 8/20\mu\text{s}$
Junction Capacitance	C_J			500	pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$

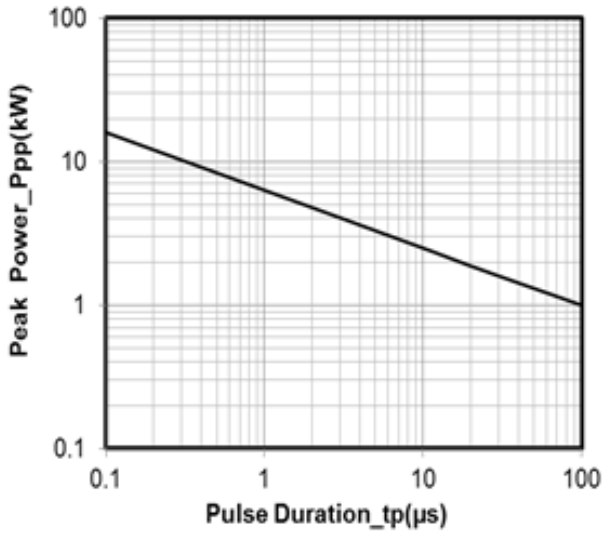
DC1571D3UH (Marking Code: 75D)						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V_{RWM}			15	V	
Breakdown Voltage	V_{BR}	16.5			V	$I_T = 1\text{mA}$
Reverse Leakage Current	I_R			0.1	μA	$V_{RWM} = 15\text{V}$
Forward Voltage	V_F		1.0	1.2	V	$I_F = 10\text{mA}$
Clamping Voltage	V_C			37	V	$I_{PP} = 60\text{A}$ (8 x 20 μs pulse)
Peak Pulse Current	I_{PP}			60	A	$t_p = 8/20\mu\text{s}$
Junction Capacitance	C_J			450	pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$

DC1871D3UH (Marking Code: 78D)						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V_{RWM}			18	V	
Breakdown Voltage	V_{BR}	19.6			V	$I_T = 1\text{mA}$
Reverse Leakage Current	I_R			0.1	μA	$V_{RWM} = 18\text{V}$
Forward Voltage	V_F		1.0	1.2	V	$I_F = 10\text{mA}$
Clamping Voltage	V_C			50	V	$I_{PP} = 45\text{A}$ (8 x 20 μs pulse)
Peak Pulse Current	I_{PP}			45	A	$t_p = 8/20\mu\text{s}$
Junction Capacitance	C_J			350	pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$

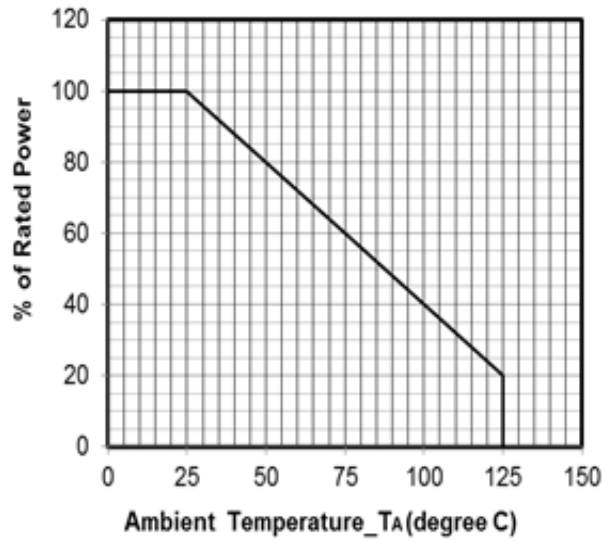
DC2471D3UH (Marking Code: 74D)						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V_{RWM}			24	V	
Breakdown Voltage	V_{BR}	26.7			V	$I_T = 1\text{mA}$
Reverse Leakage Current	I_R			0.1	μA	$V_{RWM} = 24\text{V}$
Forward Voltage	V_F		1.0	1.2	V	$I_F = 10\text{mA}$
Clamping Voltage	V_C			63	V	$I_{PP} = 35\text{A}$ (8 x 20 μs pulse)
Peak Pulse Current	I_{PP}			35	A	$t_p = 8/20\mu\text{s}$
Junction Capacitance	C_J			200	pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$

DC3671D3UH (Marking Code: 79D)						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V_{RWM}			36	V	
Breakdown Voltage	V_{BR}	37			V	$I_T = 1\text{mA}$
Reverse Leakage Current	I_R			0.1	μA	$V_{RWM} = 36\text{V}$
Forward Voltage	V_F		1.0	1.2	V	$I_F = 10\text{mA}$
Clamping Voltage	V_C			80	V	$I_{PP} = 25\text{A}$ (8 x 20 μs pulse)
Peak Pulse Current	I_{PP}			25	A	$t_p = 8/20\mu\text{s}$
Junction Capacitance	C_J			150	pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$

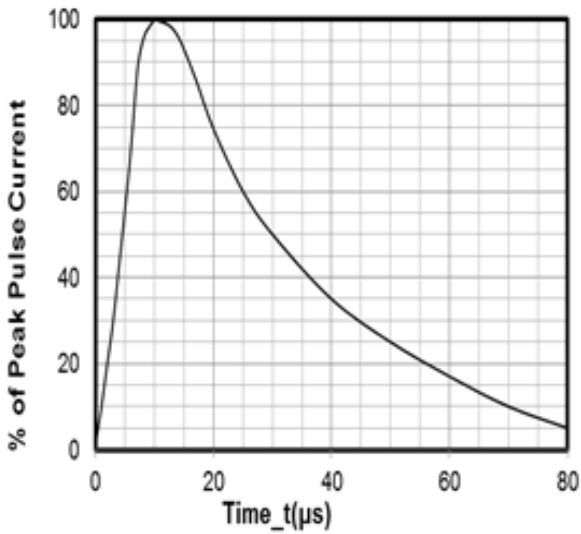
Typical Performance Characteristics (TA=25°C unless otherwise Specified)



Junction Capacitance vs. Reverse Voltage

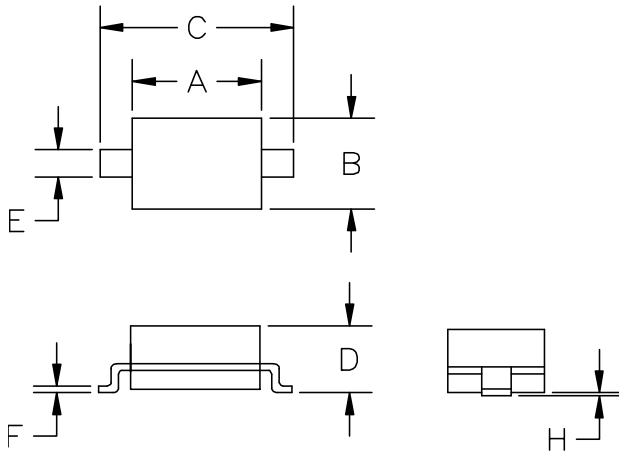


Power Derating Curve



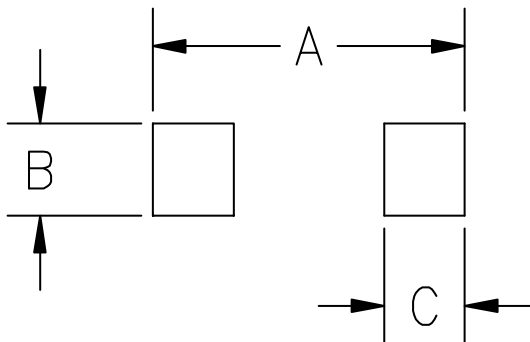
8 X 20 s Pulse Waveform

SOD-323 Package Outline Drawing



SYM	DIMENSIONS			
	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.50	1.80	0.060	0.071
B	1.20	1.40	0.045	0.054
C	2.30	2.70	0.090	0.107
D	-	1.10	-	0.043
E	0.30	0.40	0.012	0.016
F	0.10	0.25	0.004	0.010
H	-	0.10	-	0.004

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
A	3.15	0.120
B	0.80	0.031
C	0.80	0.031

Contact Information

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